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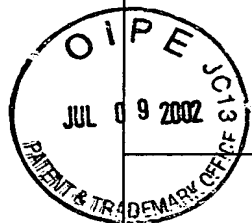
Sheet 1 of 1

FORM PTO-1449 (SUBSTITUTE)

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICEAttorney Docket No.:
GR 98 P 2314 PApplic. No.
09/781,173

Applicant

Siegfried Schwarzl

Filing Date
February 12, 2001Group Art Unit
2824INFORMATION DISCLOSURE
STATEMENT BY APPLICANT
(37 CFR 1.98(b))

U.S. PATENT DOCUMENTS

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
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	J						
	K						
	L						
	M						
	N						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

ap	O ✓	Stefan Mengel: "Technologieanalyse XMR-Technologien Technologie-Früherkennung" [technology analysis XMR-technologies, early recognition of technology], VDI-Technologiezentrum Physikalische Technologie, Düsseldorf, 1997, pp. 1-80
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ap	B	5,039,655	08/13/91	Pisharody	505	170	
ap	C	5,587,943	12/24/96	Torok et al.	365	158	
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		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES NO
ap	J	0 776 011 A2	05/28/97	Europe	_____	_____	X
ap	K	0 776 011 A3 ✓	11/19/97	Europe	_____	_____	X
ap	L	0 875 901 A2 ✓	11/04/98	Europe	_____	_____	X
ap	M	0 875 901 A3 ✓	11/03/99	Europe	_____	_____	X
ap	N	02 093 373 ✓	04/04/90	Japan	_____	_____	X

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ap	O ✓	Mark H. Kryder et al.: "Magnetic Properties and Domain Structures in Narrow NiFe Stripes", IEEE Transactions on Magnetism, Vol. Mag-16, No. 1, January 1980, pp. 99-103
ap	P ✓	D.D. Tang et al.: "Spin-Valve RAM Cell", IEEE Transactions on Magnetism, Vol. 31, No. 6, November 1995, pp. 3206-3208

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ap	J	10 004 227 A ✓	01/06/98	Japan	—	—	X
ap	K	10 162 326 A ✓	06/19/98	Japan	—	—	X
ap	L	10 190 090 A ✓	07/21/98	Japan	—	—	X
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ap	O ✓	J.M. Daughton: "Magnetic tunneling applied to memory (invited)", J. Appl. Phys. Vol. 81 No. 8, April 15, 1997, pp. 3758-3763
ap	P ✓	Yu Lu et al.: "Shape-anisotropy-controlled magnetoresistive response in magnetic tunnel junctions", Appl. Phys. Lett. Vol. 70 No. 19, May 1997, pp. 2610-2612

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ap	O ✓	Haruki Yamane et al.: "Differential type giant magnetoresistive memory using spin-valve film with a NiO pinning layer", Journal of Applied Physics, Volume 83, No. 9, May 1, 1998, pp. 4862-4868
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